



PATENT
5586D-6885 (81784.0182)

22/C
11-2002
NP
C/m

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Kiyoshi YONEDA et al.

Serial No: 09/148,606

Filed: September 4, 1998

For: SEMICONDUCTOR DEVICE HAVING A
LASER-ANNEALED SEMICONDUCTOR
DEVICE, DISPLAY DEVICE AND LIQUID
CRYSTAL DISPLAY DEVICE

Art Unit: 2874

Examiner: Ali A. Zamani

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AMENDMENT

Commissioner for Patents
Washington, D.C. 20231

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Technology Center 2600

Dear Sir:

In response to the Office Action dated May 8, 2002, the period for response to
which is being extended from August 8, 2002 to November 8, 2002, by the
accompanying Petition, please amend the above-identified application as follows:

IN THE CLAIMS:

Rewrite claim 1 as follows:

- Sub D17
CI
Contd
1. (Twice Amended) A semiconductor device in which a plurality of
semiconductor elements are formed on a substrate, wherein
in at least semiconductor elements, among said plurality of
semiconductor elements, that samples data to be supplied to other semiconductor
elements, a channel width of a channel region formed in a semiconductor layer to
which laser annealing is applied is larger than a channel length thereof, and a
channel width direction is neither vertical to nor parallel with regard to a side
direction of said substrate.